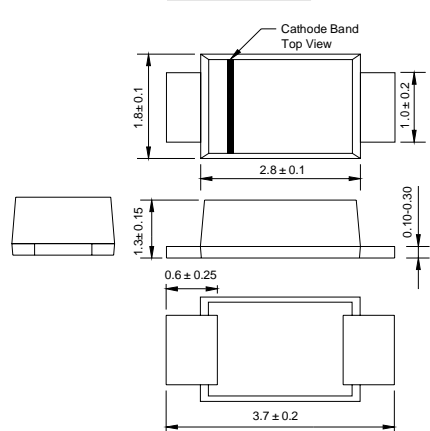
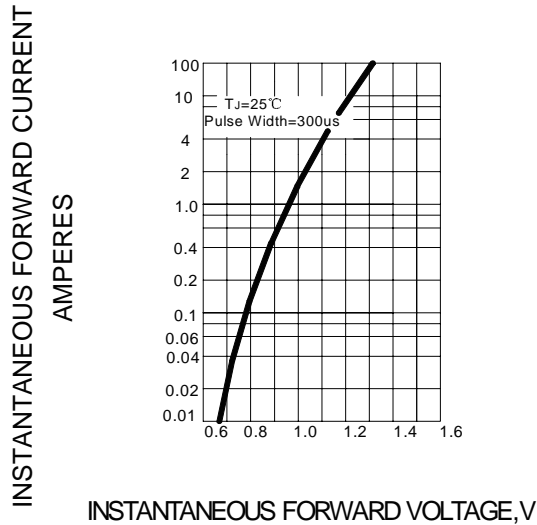


# FR101 THRU FR107

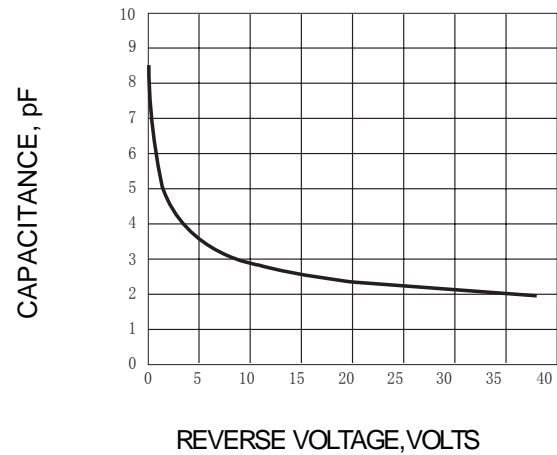
SOD-123FL		<b>FEATURES</b>								
 <p style="text-align: center;">Dimensions in millimeters</p>		<ul style="list-style-type: none"> <li>◆ Glass passivated device</li> <li>◆ Ideal for surface mouted applications</li> <li>◆ Low reverse leakage</li> <li>◆ Metallurgically bonded construction</li> <li>◆ High temperature soldering guaranteed: 250°C/10 seconds,0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension</li> </ul>								
		<b>MECHANICAL DATA</b>								
		<p><b>Case:</b> JEDEC SOD-123FL molded plastic body over passivated chip  <b>Terminals:</b> Solderable per MIL-STD-750, Method 2026  <b>Polarity:</b> Color band denotes cathode end  <b>Mounting Position:</b> Any  <b>Weight:</b>0.0007 ounce, 0.02 grams</p>								
<b>MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS</b>										
Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.										
Catalog Number	SYMBOLS	FR101 F1	FR102 F2	FR103 F3	FR104 F4	FR105 F5	FR106 F6	FR107 F7	UNITS	
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	VOLTS	
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	VOLTS	
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	VOLTS	
Maximum average forward rectified current at $T_A=65^\circ\text{C}$ (NOTE 1)	$I_{(AV)}$	1.0							Amp	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) $T_L=25^\circ\text{C}$	$I_{FSM}$	25.0							Amps	
Maximum instantaneous forward voltage at 1.0A	$V_F$	1.3							Volts	
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=125^\circ\text{C}$	$I_R$	10.0 50.0							$\mu\text{A}$	
Maximum reverse recovery time (NOTE 2)	$t_{rr}$	150				250	500		ns	
Typical junction capacitance (NOTE 3)	$C_J$	4							pF	
Typical thermal resistance (NOTE 4)	$R_{\theta JA}$	180							K/W	
Operating junction and storage temperature range	$T_J, T_{STG}$	-50 to +150							$^\circ\text{C}$	
<p><b>Note:</b> 1. Averaged over any 20ms period.                  2. Measured with <math>I_F=0.5\text{A}</math>, <math>I_R=1\text{A}</math>, <math>I_{rr}=0.25\text{A}</math>.                  3. Measured at 1MHz and applied reverse voltage of 4.0V D.C.                  4. Thermal resistance junction to ambient, 6.0 mm<sup>2</sup> copper pads to each terminal.</p>										

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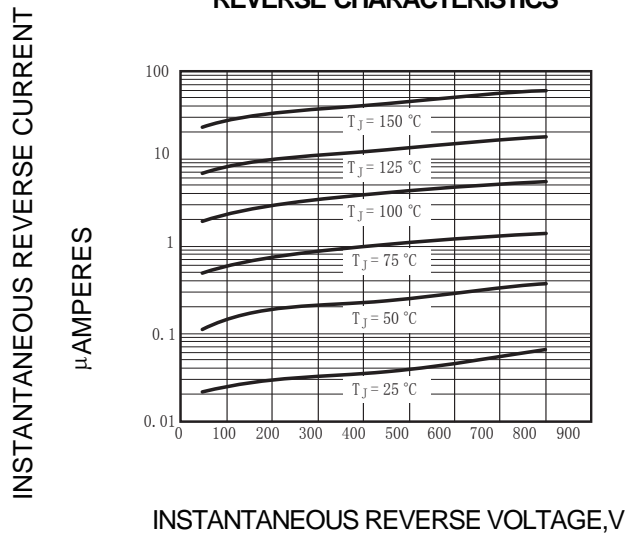
**FIG.1 – TYPICAL FORWARD CHARACTERISTIC**



**FIG.2 – TYPICAL JUNCTION CAPACITANCE**



**FIG.3 – TYPICAL INSTANTANEOUS REVERSE CHARACTERISTICS**



**FIG.4 – FORWARD DERATING CURVE**

